

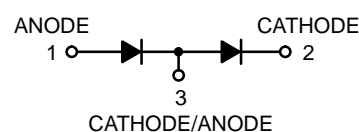
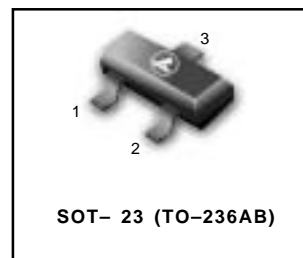
# High Voltage Switching Diode

**LBAS21SLT1**
**FEATURE**

- Pb-Free Package is available.

**MAXIMUM RATINGS**

| Rating                     | Symbol          | Value | Unit |
|----------------------------|-----------------|-------|------|
| Continuous Reverse Voltage | $V_R$           | 250   | Vdc  |
| Peak Forward Current       | $I_F$           | 225   | mAdc |
| Peak Forward Surge Current | $I_{FM(surge)}$ | 625   | mAdc |


**THERMAL CHARACTERISTICS**

| Characteristic   | Symbol          | Max         | Unit               |
|--|-----------------|-------------|--------------------|
| Total Device Dissipation FR-5 Board, (1)<br>$T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$        | $P_D$           | 225         | mW                 |
| Thermal Resistance, Junction to Ambient  | $R_{\theta JA}$ | 556         | $^\circ\text{C/W}$ |
| Total Device Dissipation<br>Alumina Substrate, (2) $T_A = 25^\circ\text{C}$<br>Derate above $25^\circ\text{C}$ | $P_D$           | 300         | mW                 |
| Thermal Resistance, Junction to Ambient  | $R_{\theta JA}$ | 417         | $^\circ\text{C/W}$ |
| Junction and Storage Temperature   | $T_J, T_{stg}$  | -55 to +150 | $^\circ\text{C}$   |

**ELECTRICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$  unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|----------------|--------|-----|-----|------|
|----------------|--------|-----|-----|------|

**OFF CHARACTERISTICS**

|  |            |     |              |                 |
|--|------------|-----|--------------|-----------------|
| Reverse Voltage Leakage Current<br>( $V_R = 200\text{Vdc}$ )<br>( $V_R = 200\text{Vdc}, T_J = 150^\circ\text{C}$ ) | $I_R$      | —   | 0.1<br>100   | $\mu\text{Adc}$ |
| Reverse Breakdown Voltage<br>( $I_{BR} = 100\ \mu\text{Adc}$ )   | $V_{(BR)}$ | 250 | —            | Vdc             |
| Forward Voltage<br>( $I_F = 100\ \text{mAdc}$ )<br>( $I_F = 200\ \text{mAdc}$ )                                    | $V_F$      | —   | 1000<br>1250 | mV              |
| Diode Capacitance<br>( $V_R = 0, f = 1.0\ \text{MHz}$ )  | $C_D$      | —   | 5.0          | pF              |
| Reverse Recovery Time<br>( $I_F = I_R = 30\ \text{mAdc}, R_L = 100\ \Omega$ )                                      | $t_{rr}$   | —   | 50           | ns              |

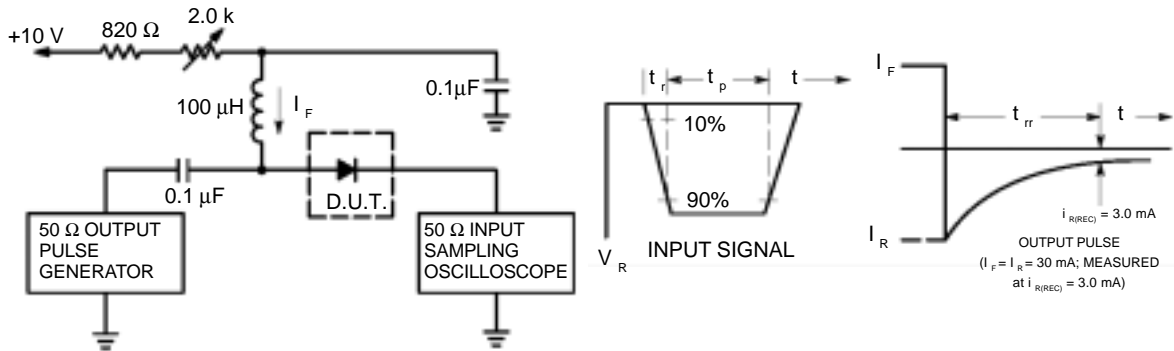
 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.

 2. Alumina =  $0.4 \times 0.3 \times 0.024$  in. 99.5% alumina.

**DEVICE MARKING AND ORDERING INFORMATION**

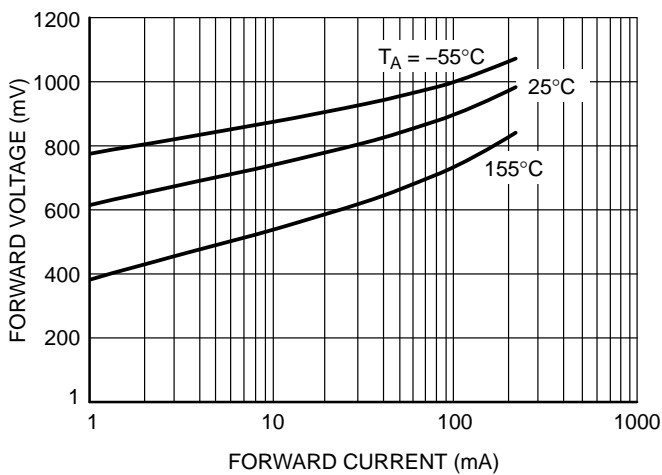
| Device      | Marking         | Shipping       |
|-------------|-----------------|----------------|
| LBAS21SLT1  | JT              | 3000/Tape&Reel |
| LBAS21SLT1G | JT<br>(Pb-Free) | 3000/Tape&Reel |

**LBAS21SLT1**

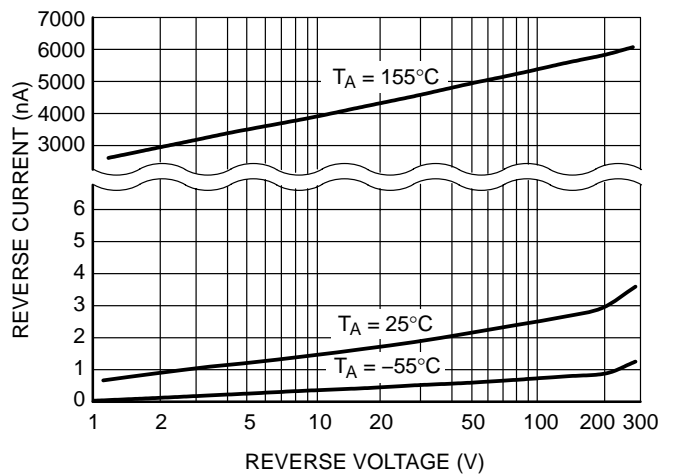


- Notes: 1. A 2.0 kΩ variable resistor adjusted for a Forward Current ( $I_F$ ) of 30 mA.  
 2. Input pulse is adjusted so  $I_{R(\text{peak})}$  is equal to 30 mA.  
 3.  $t_p \gg t_{rr}$

**Figure 1. Recovery Time Equivalent Test Circuit**



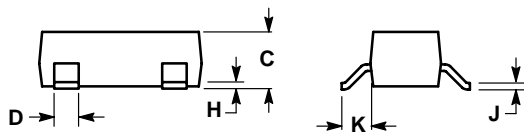
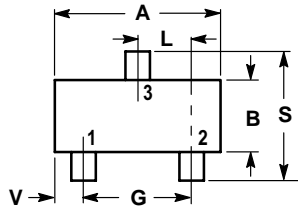
**Figure 2. Forward Voltage**



**Figure 3. Reverse Leakage**

**LBAS21SLT1**

**SOT-23**



NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.

| DIM | INCHES |        | MILLIMETERS |       |
|-----|--------|--------|-------------|-------|
|     | MIN    | MAX    | MIN         | MAX   |
| A   | 0.1102 | 0.1197 | 2.80        | 3.04  |
| B   | 0.0472 | 0.0551 | 1.20        | 1.40  |
| C   | 0.0350 | 0.0440 | 0.89        | 1.11  |
| D   | 0.0150 | 0.0200 | 0.37        | 0.50  |
| G   | 0.0701 | 0.0807 | 1.78        | 2.04  |
| H   | 0.0005 | 0.0040 | 0.013       | 0.100 |
| J   | 0.0034 | 0.0070 | 0.085       | 0.177 |
| K   | 0.0140 | 0.0285 | 0.35        | 0.69  |
| L   | 0.0350 | 0.0401 | 0.89        | 1.02  |
| S   | 0.0830 | 0.1039 | 2.10        | 2.64  |
| V   | 0.0177 | 0.0236 | 0.45        | 0.60  |

